L Number	Hits	Search Text	DB	Time stamp
1	1659	438/241,245,258,259,266.ccls.	USPAT; US-PGPUB	2003/11/19 14:35
2	601	438/241,245,258,259,266.ccls. and memory and peripheral	USPAT; US-PGPUB	2003/11/19 14:37
3	425	(438/241,245,258,259,266.ccls. and memory and peripheral) and @ad<20010112	USPAT; US-PGPUB	2003/11/19 14:36
4	1328	257/316,326.ccls.	USPAT; US-PGPUB	2003/11/19 14:36
5	380	257/316,326.ccls. and memory and peripheral	USPAT; US-PGPUB	2003/11/19 14:36
6	302	(257/316,326.ccls. and memory and peripheral) and @ad<20010112	USPAT; US-PGPUB	2003/11/19 14:37
7	278	((257/316,326.ccls. and memory and peripheral) and @ad<20010112) not ((438/241,245,258,259,266.ccls. and memory and peripheral) and @ad<20010112)	USPAT; US-PGPUB	2003/11/19 14:36
8	1112	memory and peripheral and Samsung	USPAT; US-PGPUB	2003/11/19 14:54
9	821	(memory and peripheral and Samsung) and @ad<20010112	USPAT; US-PGPUB	2003/11/19 14:40
10	174	((memory and peripheral and Samsung) and @ad<20010112) and polysilicon and transistor	USPAT; US-PGPUB	2003/11/19 14:54
11	154	(((memory and peripheral and Samsung) and @ad<20010112) and polysilicon and transistor) and (source or drain)	USPAT; US-PGPUB	2003/11/19 14:41
12	261	memory and peripheral and Samsung	EPO; JPO; DERWENT; IBM_TDB	2003/11/19 14:54
13	8	(memory and peripheral and Samsung) and polysilicon and transistor	EPO; JPO; DERWENT; IBM_TDB	2003/11/19 14:55

C:\APPS\EAST\Workspaces\09779123.wsp